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**Product data sheet** 

## 1. General description

Ultrafast power diode in a SOD132 (SMB) surface-mountable plastic package.

## 2. Features and benefits

- Low on-state loss
- Low leakage current
- Low thermal resistance
- Surface-mountable package
- Reduces switching losses in associated MOSFET or IGBT

## 3. Applications

- Buck and Boost converter
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- Inverter freewheeling and protection diode

## 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage			-	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>lead</sub> ≤ 115 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3		-	-	3	A
Static charact	eristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 3 A; T <sub>j</sub> = 150 °C; <u>Fig. 7</u>		-	0.8	1	V
Dynamic characteristics							
t <sub>rr</sub>	reverse recovery time	$I_F$ = 1 A; $V_R$ = 30 V; $dI_F/dt$ = 50 A/µs; $T_j$ = 25 °C; Ramp Recovery; <u>Fig. 8</u>		-	-	75	ns





Ultrafast power diode

## 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		K-K-A
2	A	anode	1 2 SOD132	001aaa020

## 6. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
NURS360B	SOD132	Hermetically sealed plastic package; SMB; 2 leads	SOD132			

## 7. Marking

Table 4. Marking codes	
Type number	Marking code
NURS360B	NURS360B

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

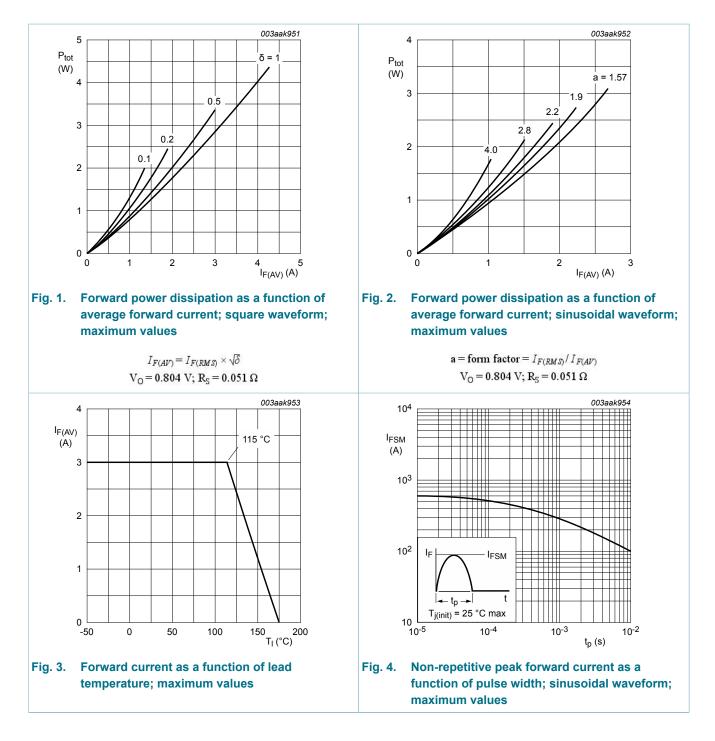
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	600	V
V <sub>RWM</sub>	crest working reverse voltage		-	600	V
V <sub>R</sub>	reverse voltage	DC	-	600	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ; T <sub>lead</sub> ≤ 115 °C; square-wave pulse; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	3	A
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 $\mu s;$ square-wave pulse	-	6	А
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	100	А
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	110	A
T <sub>stg</sub>	storage temperature		-65	175	°C
Tj	junction temperature		-	175	°C

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## 9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	mounted on a minimum footprint printed-circuit board (FR4); Fig. 5		-	14	-	K/W

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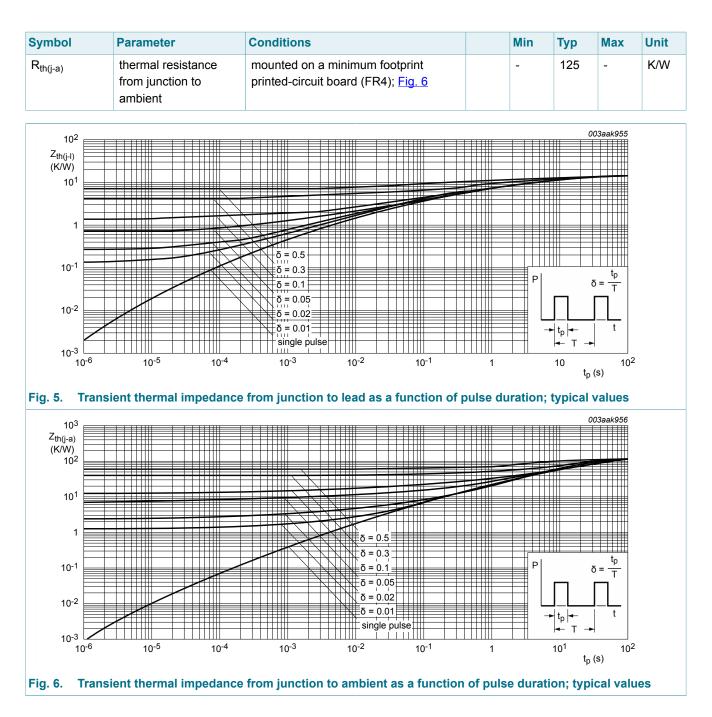
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## **10. Characteristics**

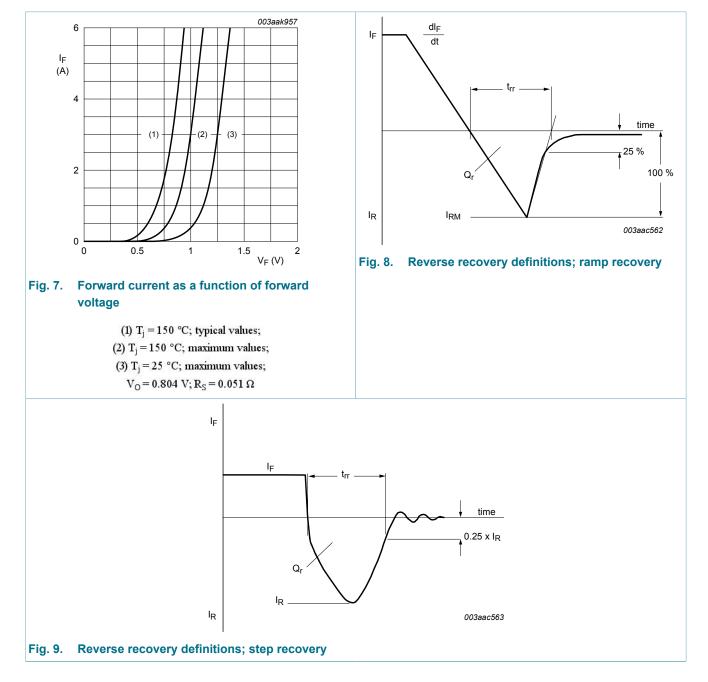
Table 7. 0	Characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Static chara	acteristics						
V <sub>F</sub> forward voltage	I <sub>F</sub> = 3 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>		-	-	1.25	V	
		I <sub>F</sub> = 3 A; T <sub>j</sub> = 150 °C; <u>Fig. 7</u>		-	0.8	1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C		-	-	2.5	μA
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 150 °C	-	-	250	μA
Dynamic char	acteristics	·				
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Ramp Recovery; Fig. 8}$	-	-	75	ns
		$I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{R(meas)} = 0.25 \text{ A};$ $T_j = 25 \text{ °C}; \text{ Step Recovery}; Fig. 9$	-	-	50	ns

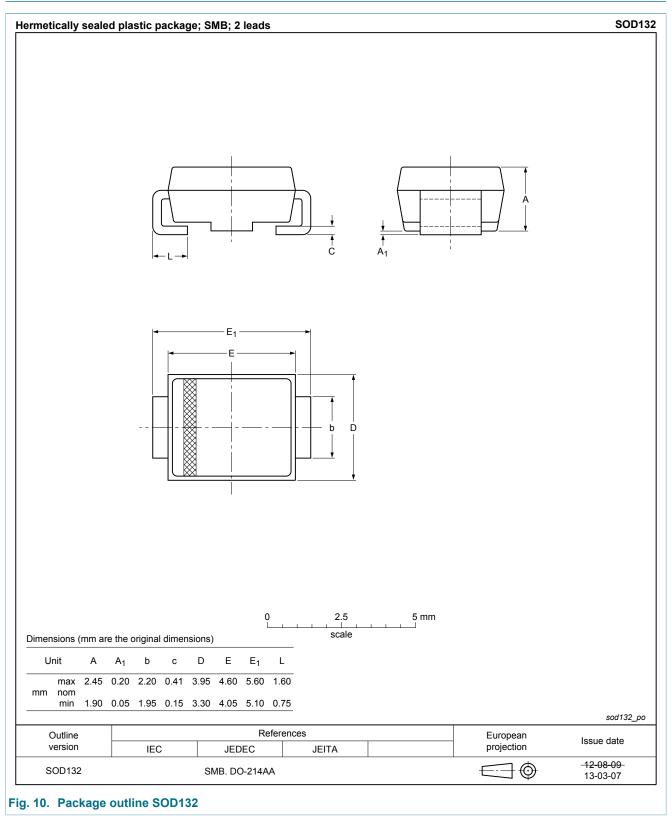


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## 11. Package outline



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## 12. Legal information

#### 12.1 Data sheet status

Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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#### Ultrafast power diode

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